Text Book:Microelectronic Circuits- 4th edition, 1998Authors:Sedra / Smith

The following chapters and sections will be covered:

Section		Chapter three	Page number
Introduction			
3.1			123-131
3.2			131-137
3.3			137-155
3.4			155-163
3.5			163-168 and 170
		Chapter four	
Introduction			
4.1			222-223
4.2			223-232
4.3			232-233
4.4			234-238
4.5			238-241
4.6			241-253
4.7			253-259
4.8			259-261, 262-264 and 322-323
4.9			272-276
4.12			295-303
		Chapter five	
Introduction			
5.1			354-361 and 364-365
5.2			366-374
5.3			376-380
5.4			380-388
5.5			389-397
5.11			447
Grading			
First midterm	20		
Second midterm	20		
Homeworks	10		
Quizzes	10		
Final	40		

Course Objectives

This is a required course for electrical engineering and computer engineering majors. The objective of this course is to introduce students to the basic physics and operation of semiconductor devices as well as some simple applications. Students will gain good background for more advanced courses

	Course outcome	abet (a-k)
1	Students will demonstrate an understanding of basic semiconductor	a, e
	theory, including the concepts of resistivity, conductivity, intrinsic	
	semiconductor, doping, majority and minority carriers, energy band diagram, drift and diffusion	
2	Students will demonstrate an understanding of pn junction operation,	a, e
	biasing, and current.	
3	Students will demonstrate an understanding of nonlinear devices through	a
	ideal diode behavior	
4	Students will demonstrate an understanding of the use of on-off behavior	a, c,e
	of the diode on some applications such as rectifiers and logic gates.	
	Students will demonstrate an understanding of the internal	a,e
	semiconductor characteristics of diodes and BJT/MOSFET transistors	
5	Draw the I-V characteristics of a PN junction diode, BJT and MOSFET.	а
6	Indicate different regions of operation of a diode and operating modes of	а
	BJTs and MOSFETs.	
7	Students can apply electric network theory to semiconductor circuits:	a, e, k
	diodes, transistors, amplifiers and diode logic gates.	
8	Students will be able to distinguish bias from signal	a, e, k
9	Students will be able to analyze and design basic diode and transistor	a,c,e,k
	circuits for large and small signal operation.	
10	Student will demonstrate a basic understanding of the application of the	a,c,e,k
10	transistor (BJT & MOSFET) as an amplifier or switche.	и,с,с,к